DECLARATION FOR PATENT APPLICATION AND POWER OF ATTORNEY

(Under 37 CFR § 1.63; includes reference to PCT International Applications)

As the below named inventors, we hereby declare that:

Our residence, post office address and citizenship are as stated below next to our names.

We believe we are the original, first and joint inventors of the subject matter which is claimed and for which a patent is sought on the invention ENTITLED:

SEMICONDUCTOR DEVICE WITH A CAVITY THEREIN AND A METHOD OF MANUFACTURING THE SAME

the specification	n of which:				
	is attached hereto was filed on as: United States Application as a National Phase or C PCT Application No and designating the U.S with amendments throu	Continuation or Co , filed S., and published a		onal of	
			d understand the contents nendment referred to above.	s of the above-ide	ntified
	-		ed States Patent and Traden itle 37, Code of Federal Reg		nation
application(s) for one country other to country other to	or patent or inventor's coner than the United State patent or inventor's cer	ertificate or of an te of America list rtificate or any Po of America filed b	er Title 35, United States C y PCT International applica- ted below and have also ide CT International application by us on the same subject rated:	tion(s) designating a entified below any f as designating at lea	it least foreign ist one
Prior Foreign/P	CT Application(s) [list a	idditional applicat	ions on separate page]:	Priority Claimed:	
Country (or Japan		<u>n Number:</u> 73409	Filed (Day/Month/Year) September 19, 2002	Yes No	
We her	eby claim the benefit und	der 35 U.S.C. §11	9(e) of any United States ap	plication listed below	v:
(Applic	ation Number)	(Filing Date)			
			United States Code § 1 nating the United States of		

We hereby claim the benefit under Title 35, United States Code § 120 of any United States application(s) or PCT international application(s) designating the United States of America that is/are listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in that/those prior application(s) in the manner provided by the first paragraph of Title 35, United States Code § 112, we acknowledge the duty to disclose to the United States Patent and Trademark Office all information known to us

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to be material to patentability as defined in Title 37, Code of Federal Regulations, § 1.56 which became available between the filing date of the prior application and the national or PCT international filing date of this application:

Prior U.S. (or U.S.-designating PCT) Application(s) [list additional applications on separate page]:

U.S. Serial No.: Filed (Day/Month/Year) PCT Application No. Status (patented, pending, abandoned)

We hereby appoint Edgar H. Haug, Registration No. 29,309, and Grace L. Pan, Registration No. 39,440, and Frommer Lawrence & Haug LLP, or their duly appointed associate, our attorneys, with full power of substitution and revocation, to prosecute this application, to make alterations and amendments therein, to file continuation and divisional applications thereof, to receive the Patent, and to transact all business in the Patent and Trademark Office and in the Courts in connection therewith, and to insert the Serial Number of the application in the space provided above, and specify that all communications about the application are to be directed to the following correspondence address:

Grace L. Pan, Esq. c/o FROMMER LAWRENCE & HAUG LLP 745 Fifth Avenue New York, NY 10151

INIVENITOD C.

Direct all telephone calls to: (212) 588-0800

to the attention of: Grace L. Pan

We hereby declare that all statements made herein of our own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

HVVLIVI ORG.			
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